

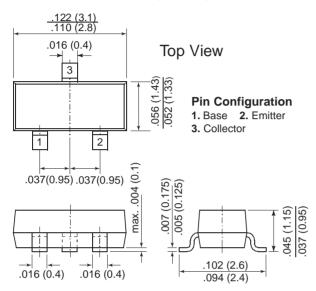
#### **New Product**

Vishay Semiconductors formerly General Semiconductor



## **Small Signal Transistors (PNP)**

#### TO-236AB (SOT-23)

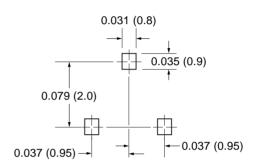


Dimensions in inches and (millimeters)

#### **Features**

- PNP Silicon Epitaxial Planar Transistors
- Suited for low level, low noise, low frequency applications in hybrid cicuits.
- Low Current, Low Voltage.
- As complementary types, BCW60 Series NPN transistors are recommended.

#### **Mounting Pad Layout**



#### **Mechanical Data**

Case: SOT-23 Plastic Package

 Weight:
 approx. 0.008g

 Marking
 BCW61A = BA

 Code:
 BCW61B = BB

 BCW61C = BC

 BCW61D = BD

#### **Packaging Codes/Options:**

E8/10K per 13" reel (8mm tape), 30K/box E9/3K per 7" reel (8mm tape), 30K/box

### Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage (VBE = 0)	-Vces	32	V
Collector-Emitter Voltage	-VCEO	32	V
Emitter-Base Voltage	-VEBO	5.0	V
Collector Current (DC)	-Ic	100	mA
Peak Collector Current	-Ісм	200	mA
Base Current (DC)	-IB	50	mA
Power Dissipation	Ptot	250	mW
Maximum Junction Temperature	Tj	150	°C
Storage Temperature Range	Tstg	-65 to +150	°C
Thermal Resistance, Junction to Ambient Air	R <sub>θ</sub> JA	500 <sup>(1)</sup>	°C/W

#### Note

(1) Mounted on FR-4 printed-ciruit board.

## **BCW61 Series**

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## Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

	3	Symbol	Min.	TYP.	Max.	Unit
DC Current Gain						
at $-VCE = 5 V$ , $-IC = 10 \mu A$	BCW61A	hFE	_	_	_	_
at $-VCE = 5 \text{ V}$ , $-IC = 10 \mu\text{A}$	BCW61B	hFE	30	_	_	_
at $-VCE = 5 \text{ V}, -IC = 10 \mu\text{A}$	BCW61C	hFE	40	_	_	_
at $-VCE = 5 \text{ V}, -IC = 10 \mu\text{A}$	BCW61D	hFE	100	_	_	_
•						
at $-VCE = 5 V$ , $-IC = 2 mA$	BCW61A	hFE	120	_	220	_
at $-VCE = 5 V$ , $-IC = 2 mA$	BCW61B	hFE	180	_	310	_
at $-VCE = 5 V$ , $-IC = 2 mA$	BCW61C	hFE	250	_	460	-
at $-VCE = 5 V$ , $-IC = 2 mA$	BCW61D	hFE	380	_	630	_
	D014/04 A					
at $-VCE = 1 V$ , $-IC = 50 mA$	BCW61A	hFE	60	_	_	_
at $-VCE = 1 V$ , $-IC = 50 mA$	BCW61B	hFE	80	_	_	_
at $-VCE = 1 V$ , $-IC = 50 mA$	BCW61C	hFE	100	_	_	_
at -VcE = 1 V, -Ic = 50 mA	BCW61D	hFE	110	_	_	_
Collector-Emitter Saturation Voltage						
at $-I_C = 10 \text{ mA}$ , $-I_B = 0.25 \text{ mA}$		-VcEsat	60	_	250	mV
at $-I_C = 50 \text{ mA}$ , $-I_B = 1.25 \text{ mA}$		-VCEsat	120	_	550	mV
Base-Emitter Saturation Voltage						
at $-IC = 10 \text{ mA}$ , $-IB = 0.25 \text{ mA}$		-VBEsat	600	_	850	mV
at $-I_C = 50 \text{ mA}$ , $-I_B = 0.25 \text{ mA}$		-VBEsat	680	_	1050	mV
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Base-Emitter Voltage		.,		0.50		.,
at $-VCE = 5 V$ , $-IC = 2 mA$		–VBE	600	650	750	mV
at $-VCE = 5 V$ , $-IC = 10 \mu A$		–VBE	_	550	_	mV
at -VcE = 1 V, -lc = 50 mA		–VBE	_	720	_	mV
Collector-Emiter Cut-off Current						
at $-V_{CE} = 32 \text{ V}, V_{EB}=0$		-Ices	_	_	20	nA
at $-V_{CE} = 32 \text{ V}, V_{EB} = 0, T_A = 150^{\circ}\text{C}$			_	_	20	μΑ
Emitter-Base Cut-off Current						
at –VEB = 4 V, IC=0		-lebo	_	_	20	nA
·						
Gain-Bandwidth Product		fΤ	100	_	_	MHz
at -VCE = 5 V, -IC = 10 mA, f = 100 MHz						
Collector-Base Capacitance		Ссво		4.5		pF
at $-V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, I_{E}=0$		CCBO	_	4.5	_	PF
Emitter-Base Capacitance						_
at –VEB = 0.5 V, f = 1 MHz, Ic=0		Сево	_	11	_	pF
Noise Figure	VPT D 200H=	F	_	2	6	dB
at –VCE = 5 V, –IC = 200 μA, Rs = 2 kΩ, f = 100	) KHZ, D = 200HZ					
Small Signal Current Gain	BCW60A		_	200		
at $-V_{CE} = 5V$ , $-I_{C} = 2 \text{ mA}$ , $f = 1.0 \text{ kHz}$	BCW60B	h <sub>fe</sub>	_	260		
	BCW60C	1110	_	330		
	BCW60D		_	520		
Turn-on Time at $R_L = 990\Omega$ (see fig. 1)						
$-V_{CC} = 10V, -I_{C} = 10mA, -I_{B(on)} = I_{B(off)} =$	= 1mA	t <sub>on</sub>	_	85	150	ns
Turn-off Time at $R_L = 990\Omega$ (see fig. 1)	1 m A	toff	_	480	800	ns
-VCC = 10V, -IC = 10mA, -IB(on) = IB(off) = -VCC = 10V, -IC = 10mA, -IB(on) = -VCC = 10V, -IC = 10mA, -IC = 10V,	= IMA	-				<u> </u>

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Fig. 1 - Switching Waveforms

